

# CMOS/MUS INTEGRATED CIRCUIT



7929225 S G S SEMICONDUCTOR CORP

## BCD RATE MULTIPLIER

- CASCADABLE IN MULTIPLES OF 4-BITS
- SET TO 9 INPUT AND 9 DETECT OUTPUT
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V, AND 15V PARAMETRIC RATINGS
- INPUT CURRENT OF 100 nA AT 18V AND 25°C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD No. 13A, "STANDARD SPECIFICATIONS FOR DESCRIPTION OF "B" SERIES CMOS DEVICES"

The HCC 4527B (extended temperature range) and HCF 4527B (intermediate temperature range) are monolithic integrated circuit, available in 16-lead dual in-line plastic or ceramic package, and ceramic flat package.

The HCC/HCF 4527 is a low-power 4-bit digital rate multiplier that provides an output-pulse rate which is the clock-input-pulse rate multiplied by 1/10 times the BCD input. For example, when the BCD input is 8, there will be 8 output pulses for every 10 input pulses. This device may be used to perform arithmetic operations (add, subtract, divide, raise to a power), solve algebraic and differential equations, generate natural logarithms and trigonometric functions, A/D and D/A conversion, and frequency division.

## ABSOLUTE MAXIMUM RATINGS

$V_{DD}^*$	Supply voltage: HCC types HCF types	-0.5 to 20 -0.5 to 18	V V
$V_i$	Input voltage	-0.5 to $V_{DD} + 0.5$	V
$I_i$	DC input current (any one input)	$\pm 10$	mA
$P_{tot}$	Total power dissipation (per package)	200	mW
	Dissipation per output transistor for $T_{op}$ = full package-temperature range	100	mW
$T_{op}$	Operating temperature: HCC types HCF types	-55 to 125 -40 to 85	°C °C
$T_{stg}$	Storage temperature	-65 to 150	°C

\* All voltage values are referred to  $V_{SS}$  pin voltage

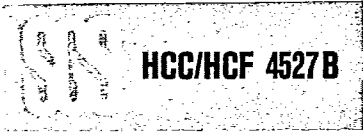
## ORDERING NUMBERS:

HCC 4527 BD for dual in-line ceramic package  
 HCC 4527 BF for dual in-line ceramic package, frit seal  
 HCC 4527 BK for ceramic flat package  
 HCF 4527 BE for dual in-line plastic package  
 HCF 4527 BF for dual in-line ceramic package, frit seal

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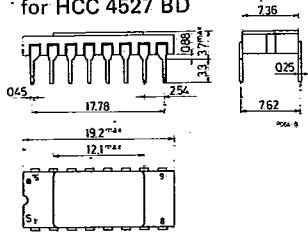
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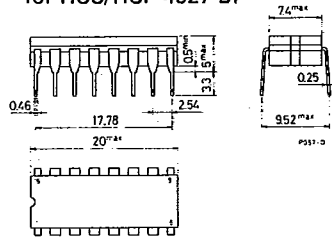
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MECHANICAL DATA(dimensions in mm)

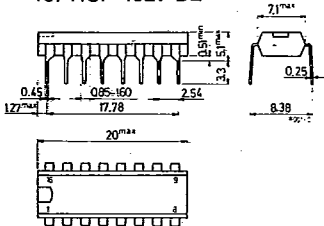
Dual in-line ceramic package for HCC 4527 BD



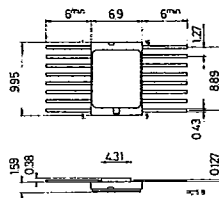
Dual in-line ceramic package for HCC/HCF 4527 BF



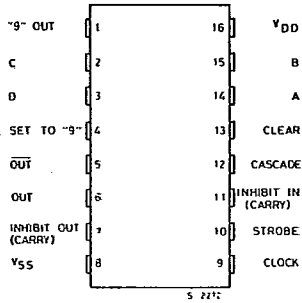
Dual in-line plastic package for HCF 4527 BE



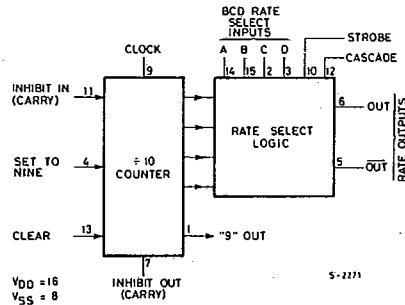
Ceramic flat package for HCC 4527 BK



CONNECTION DIAGRAM



FUNCTIONAL DIAGRAM



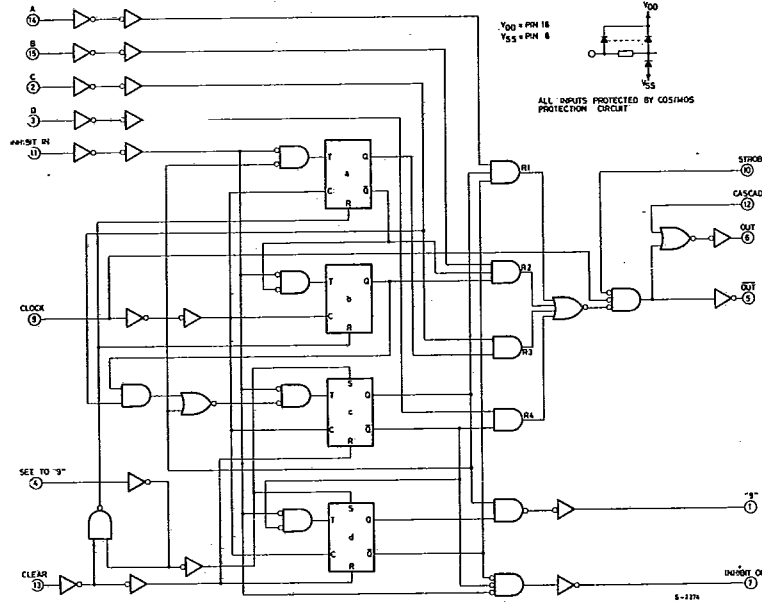
RECOMMENDED OPERATING CONDITIONS

$V_{DD}$	Supply voltage: HCC types HCF types	3 to 18 V 3 to 15 V
$V_I$	Input voltage	0 to $V_{DD}$ V
$T_{op}$	Operating temperature: HCC types HCF types	-55 to 125 °C -40 to 85 °C



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LOGIC DIAGRAM



TRUTH TABLE

INPUTS										OUTPUTS			
Number of Pulses or Input Logic Level (0 = Low; 1 = High; X = Don't Care)										Number of Pulses or Output Logic Level (L = Low; H = High)			
D	C	B	A	CLK	INH IN	STR	CAS	CLR	SET	OUT	OUT	INH OUT	"9" OUT
0	0	0	0	10	0	0	0	0	0	L	H	1	1
0	0	0	1	10	0	0	0	0	0	1	1	1	1
0	0	1	0	10	0	0	0	0	0	2	2	1	1
0	0	1	1	10	0	0	0	0	0	3	3	1	1
0	1	0	0	10	0	0	0	0	0	4	4	1	1
0	1	0	1	10	0	0	0	0	0	5	5	1	1
0	1	1	0	10	0	0	0	0	0	6	6	1	1
0	1	1	1	10	0	0	0	0	0	7	7	1	1
1	0	0	0	10	0	0	0	0	0	8	8	1	1
1	0	0	1	10	0	0	0	0	0	9	9	1	1
1	0	1	0	10	0	0	0	0	0	8	8	1	1
1	0	1	1	10	0	0	0	0	0	9	9	1	1
1	1	0	0	10	0	0	0	0	0	8	8	1	1
1	1	0	1	10	0	0	0	0	0	9	9	1	1
1	1	1	0	10	0	0	0	0	0	8	8	1	1
1	1	1	1	10	0	0	0	0	0	9	9	1	1
X	X	X	X	10	1	0	0	0	0	▲	▲	H	▲
X	X	X	X	10	0	1	0	0	0	L	●	1	1
X	X	X	X	10	0	0	1	0	0	H	●	1	1
1	X	X	X	10	0	0	0	1	0	10	10	H	L
0	X	X	X	10	0	0	0	1	0	L	H	H	L
X	X	X	X	10	0	0	0	0	1	L	H	L	H

● Output same as the first 16 lines of this truth table (depending on values of A, B, C, D).  
▲ Depends on internal state of counter.



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## STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

Parameter		Test conditions				Values						Unit		
		V <sub>I</sub> (V)	V <sub>O</sub> (V)	I <sub>O</sub>   ( $\mu$ A)	V <sub>DD</sub> (V)	T <sub>Low</sub> *		25°C			T <sub>High</sub> *			
						Min.	Max.	Min.	Typ.	Max.	Min.		Max.	
I <sub>L</sub>	Quiescent current	HCC types	0/ 5			5		5		0.04	5		150	$\mu$ A
			0/10			10		10		0.04	10		300	
			0/15			15		20		0.04	20		600	
		HCF types	0/ 5			5		20		0.04	20		150	
			0/10			10		40		0.04	40		300	
			0/15			15		80		0.04	80		600	
V <sub>OH</sub>	Output high voltage	0/ 5		< 1	5	4.95		4.95			4.95		V	
		0/10		< 1	10	9.95		9.95			9.95			
		0/15		< 1	15	14.95		14.95			14.95			
V <sub>OL</sub>	Output low voltage	5/0		< 1	5		0.05			0.05		0.05	V	
		10/0		< 1	10		0.05			0.05		0.05		
		15/0		< 1	15		0.05			0.05		0.05		
V <sub>IH</sub>	Input high voltage		0.5/4.5	< 1	5	3.5		3.5			3.5		V	
			1/9	< 1	10	7		7			7			
			1.5/13.5	< 1	15	11		11			11			
V <sub>IL</sub>	Input low voltage		4.5/0.5	< 1	5		1.5			1.5		1.5	V	
			9/1	< 1	10		3			3		3		
			13.5/1.5	< 1	15		4			4		4		
I <sub>OH</sub>	Output drive current	HCC types	0/ 5	2.5		5	-2		-1.6	-3.2		-1.15	mA	
			0/ 5	4.6		5	-0.64		-0.51	-1		-0.36		
			0/10	9.5		10	-1.6		-1.3	-2.6		-0.9		
		HCF types	0/ 5	2.5		5	-1.53		-1.36	-3.2		-1.1		
			0/ 5	4.6		5	-0.52		-0.44	-1		-0.36		
			0/10	9.5		10	-1.3		-1.1	-2.6		-0.9		
I <sub>OL</sub>	Output sink current	HCC types	0/ 5	0.4		5	0.64		0.51	1		0.36	mA	
			0/10	0.5		10	1.6		1.3	2.6		0.9		
			0/15	1.5		15	4.2		3.4	6.8		2.4		
		HCF types	0/ 5	0.4		5	0.52		0.44	1		0.36		
			0/10	0.5		10	1.3		1.1	2.6		0.9		
			0/15	1.5		15	3.6		3.0	6.8		2.4		
I <sub>IH</sub> , I <sub>IL</sub>	Input leakage current	HCC types	0/18	Any input	18		$\pm 0.1$		$\pm 10^{-5}$	$\pm 0.1$		$\pm 1$	$\mu$ A	
		HCF types	0/15		15		$\pm 0.3$		$\pm 10^{-5}$	$\pm 0.3$		$\pm 1$		
C <sub>I</sub>	Input capacitance		Any input						5	7.5		pF		

\* T<sub>Low</sub> = - 55°C for HCC device; -40°C for HCF device.\* T<sub>High</sub> = +125°C for HCC device; +85°C for HCF device.The Noise Margin for both "1" and "0" level is: 1V min. with V<sub>DD</sub> = 5V  
2V min. with V<sub>DD</sub> = 10V  
2.5V min. with V<sub>DD</sub> = 15V

**DYNAMIC ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25^{\circ}C$ ,  $C_L = 50$  pF,  $R_L = 200$  k $\Omega$ , typical temperature coefficient for all  $V_{DD}$  values is 0.3%/ $^{\circ}C$ , all input rise and fall times = 20 ns)

Parameter		Test conditions	Values			Unit	
			$V_{DD}$ (V)	Min.	Typ.		Max.
$t_{PHL}$ , $t_{PLH}$	Propagation delay time	Clock to out	5		110	220	ns
			10		55	110	
			15		45	90	
	Clock or strobe to out	5		150	300	ns	
		10		75	150		
		15		60	120		
	Clock to inhibit out high level to low level	5		320	640	ns	
		10		145	290		
		15		100	200		
	Low level to high level	5		250	500	ns	
10			100	200			
15			75	150			
Clear to out	5		380	760	ns		
	10		175	350			
	15		130	260			
Clock to "9" or "1" out	5		300	600	ns		
	10		125	250			
	15		90	180			
Cascade to out	5		90	180	ns		
	10		45	90			
	15		35	70			
Inhibit input to inhibit out	5		130	260	ns		
	10		60	120			
	15		45	90			
Set to out	5		330	660	ns		
	10		150	300			
	15		110	220			
$t_{THL}$ , $t_{TLH}$	Transition time	5		100	200	ns	
		10		50	100		
		15		40	80		
$f_{CL}$	Maximum clock frequency	5	1.2	2.4		MHz	
		10	2.5	5			
		15	3.5	7			
$t_w$	Clock pulse width	5	330	165		ns	
		10	170	85			
		15	100	50			
$t_r$ , $t_f$	Clock rise or fall time	5			15	$\mu s$	
		10			15		
		15			15		
$t_w$	Set or clear pulse width	5	160	80		ns	
		10	90	45			
		15	60	30			

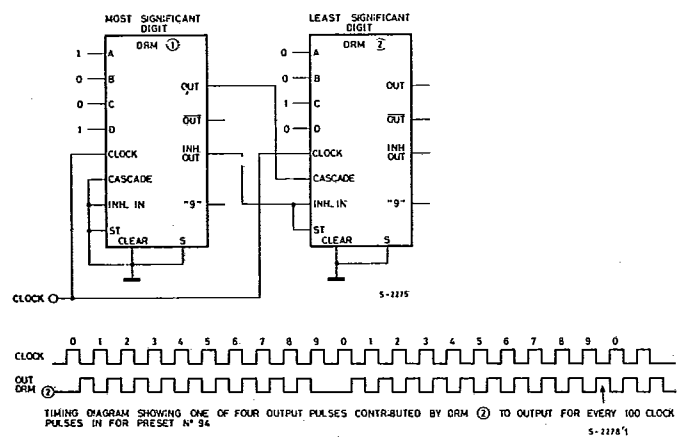
**DYNAMIC ELECTRICAL CHARACTERISTICS** (continued)

Parameter	Test conditions	Values			Unit
		V <sub>DD</sub> (V)	Min.	Typ.	
t <sub>setup</sub> Inhibit input setup time		5	100	50	ns
		10	40	20	
		15	20	10	
t <sub>R</sub> Inhibit input removal time		5	240	120	ns
		10	130	65	
		15	110	55	
t <sub>R</sub> Set removal time		5	150	75	ns
		10	80	40	
		15	50	25	
t <sub>R</sub> Clear removal time		5	60	30	ns
		10	40	20	
		15	30	15	

**APPLICATIONS NOTE**

For fractional multipliers with more than one digit, HCC/HCF 4527 devices may be cascaded in two different modes: the Add mode and the Multiply mode. See figs. 1 and 3.

Fig. 1 - Two HCC/HCF 4527B cascaded in the "Add" mode with a preset number



When two units are cascaded in Add mode and programmed to 9 and 4 respectively, the more significant unit will have 9 output pulses for every 10 input pulses and the other unit will have 4 output pulses for every 100 input pulses for a total of  $\frac{9}{10} + \frac{4}{100} = \frac{94}{100}$ .



APPLICATIONS NOTE (continued)

The Addition of two variables, A and B is instead obtained with this application:

Fig. 2 - Addition of two variables, A and B

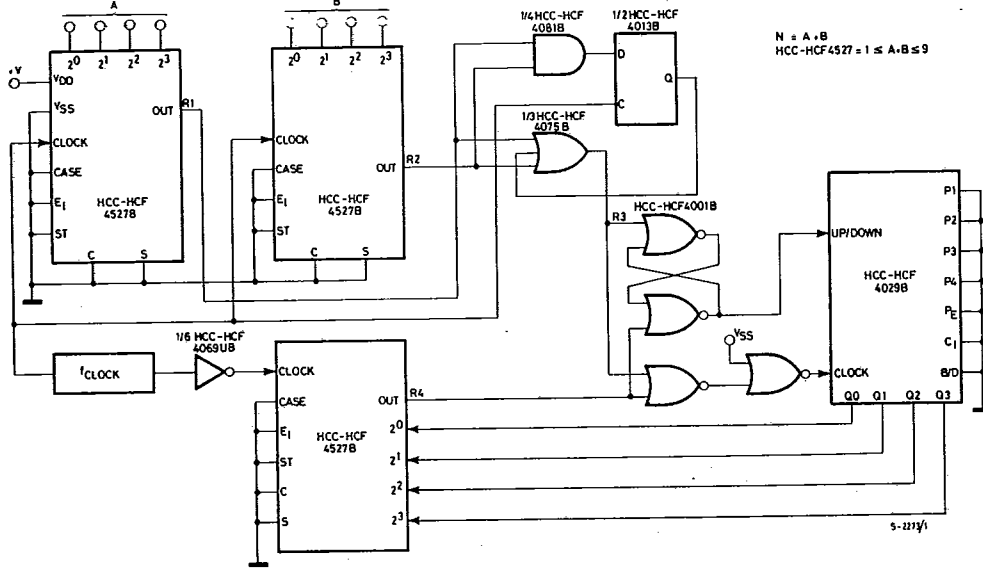
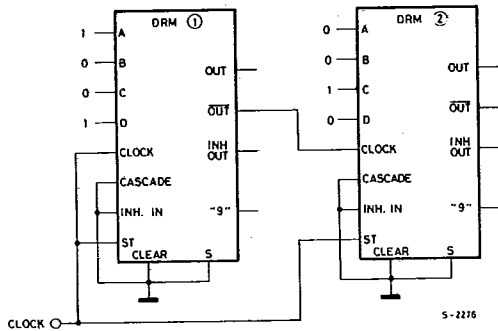


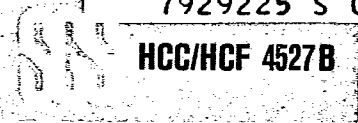
Fig. 3 - Two HCC/HCF 4527B cascaded in the "Multiply" mode with a preset number



In the Multiply mode, the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second one:  $f_{out2} = \left(\frac{4}{10}\right) \cdot f_{out1}$   $N_1 = 9$  and  $N_2 = 4$

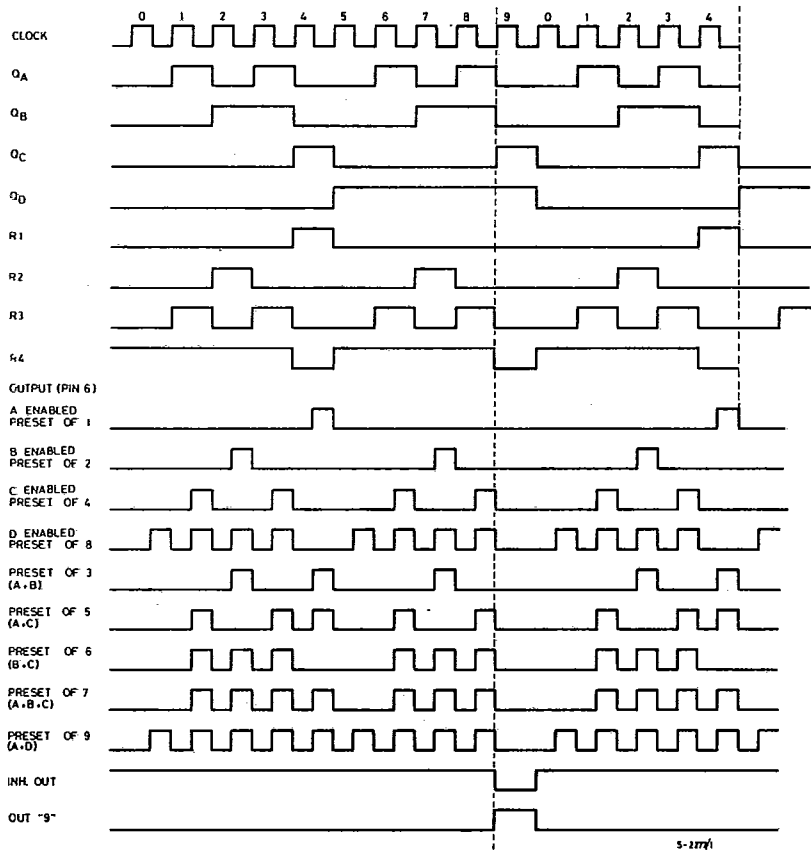
$$f_{out2} = \left(\frac{4}{10}\right) \cdot f_{out1} \quad f_{out1} = \frac{9}{10} f_{clock} \quad f_{out2} = \frac{4}{10} \times \left(\frac{9}{10} f_{clock}\right) = \frac{36}{100} f_{clock}$$

There fore 36 output pulses for every 100 clock input pulses.



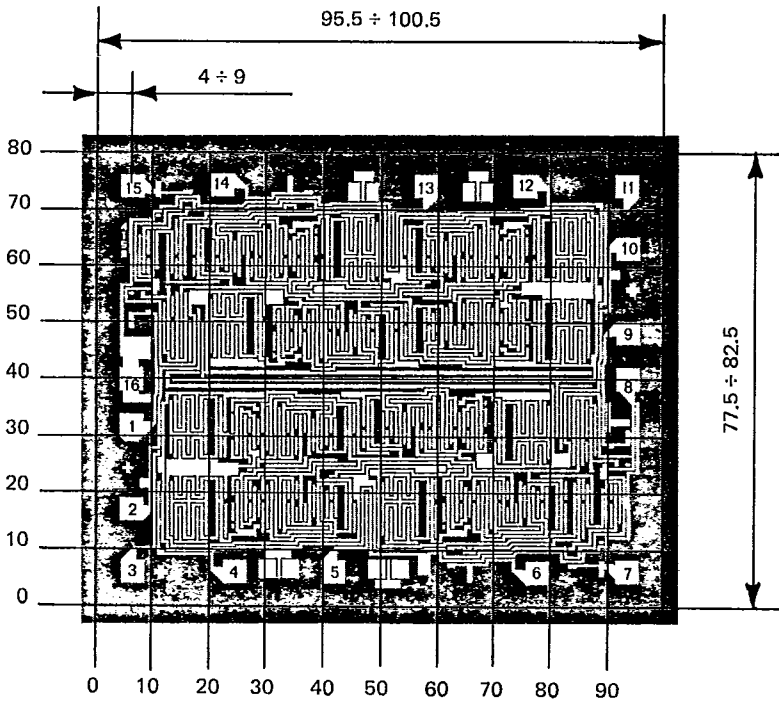
APPLICATIONS NOTE (continued)

Fig. 4 - Timing diagram (see Logic Diagram)

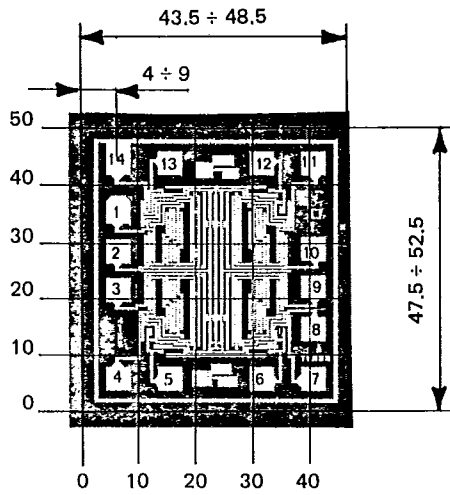


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4015B



4016B